## NSN 5961-01-282-5561

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-282-5561 **Inclosure Material:** Ceramic or glass **Overall Length:** Between 0.360 inches and 0.375 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.190 inches and 0.205 inches **Function For Which Designed:** Transient suppressor **End Application:** 6620-01-172-6946 indicator, torquemeter **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 21.6 breakdown voltage, instantaneous and 26.4 breakdown voltage, instantaneous and 19.4 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 milliamperes collector current, dc outside diameter **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: